150V NPN MEDIUM POWER TRANSISTOR IN SOT223

Features

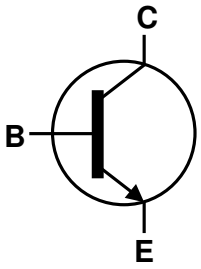
- BV_{CEO} > 150V
- I_C = 5A High Continuous Collector Current
- I_{CM} = 10A Peak Pulse Current
- Very Low Saturation Voltage $V_{CE(sat)}$ < 110mV @ 1A
- $R_{CE(sat)}$ = 50mΩ for a Low Equivalent On-Resistance
- h_{FE} Specified Up to 10A for a High Gain Hold-Up
- Complementary PNP Type: FZT955
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/**

Mechanical Data

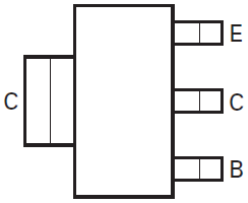
- Package: SOT223 (Type DN)
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.112 grams (Approximate)

SOT223 (Type DN)

Top View



Device Symbol



Top View
Pin-Out

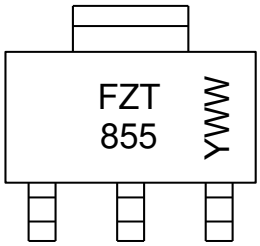
Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT855TA	Standard	FZT855	7	12	1,000

Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT223



FZT 855 = Product Type Marking Code
YWW = Date Code Marking
Y or $\overline{Y}$ = Last Digit of Year (ex: 7 = 2017)
WW or $\overline{W}\overline{W}$ = Week Code (01–53)

Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	250	V
Collector-Emitter Voltage	V_{CEO}	150	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	I_C	5	A
Peak Pulse Current	I_{CM}	10	A
Base Current	I_B	1	A

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

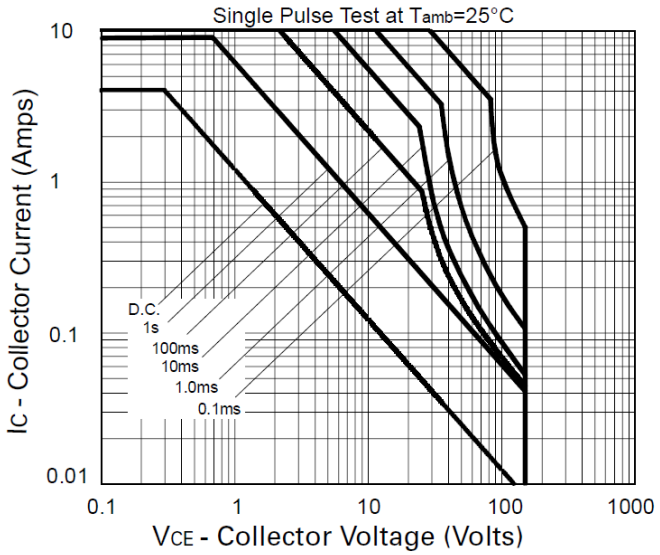
Characteristic		Symbol	Value	Unit
Power Dissipation Linear Derating Factor	(Note 5)	P_D	3.0 24	W mW/°C
	(Note 6)		1.6 12.8	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	42	°C/W
	(Note 6)	$R_{\theta JA}$	78	
Thermal Resistance Junction to Lead	(Note 7)	$R_{\theta JL}$	8.8	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 8)

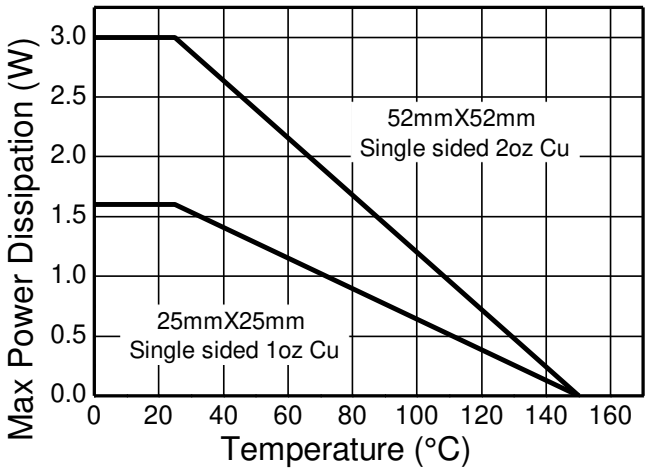
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

Notes:
5. For a device surface mounted on 52mm X 52mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; device measured when operating in steady state condition.
6. Same as Note 5, except the device is mounted on 25mm x 25mm single sided 1oz weight copper.
7. Thermal resistance from junction to solder-point (at the end of the collector lead).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

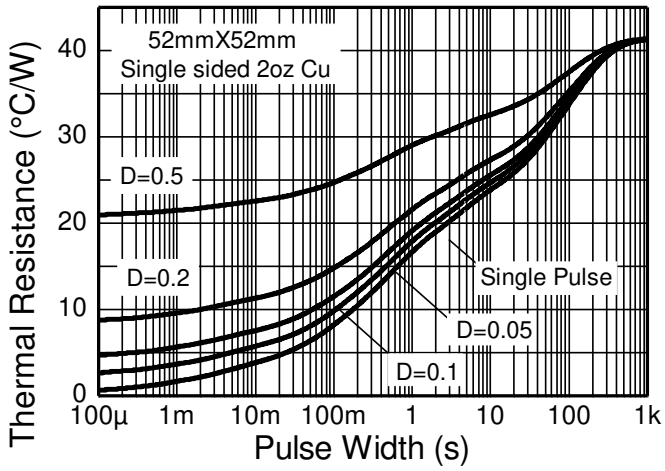
Thermal Characteristics and Derating Information



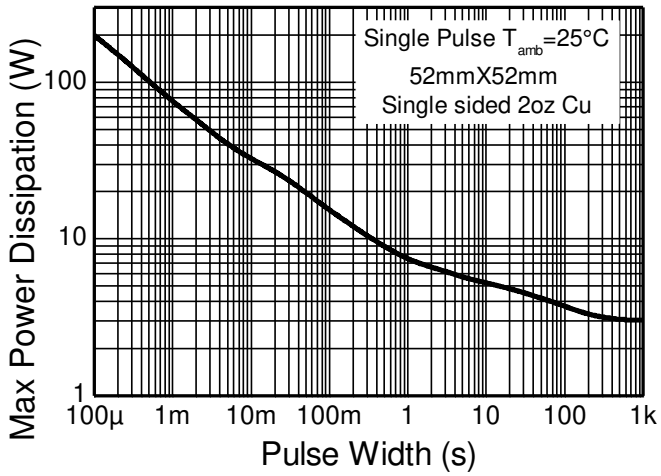
Safe Operating Area



Derating Curve



Transient Thermal Impedance



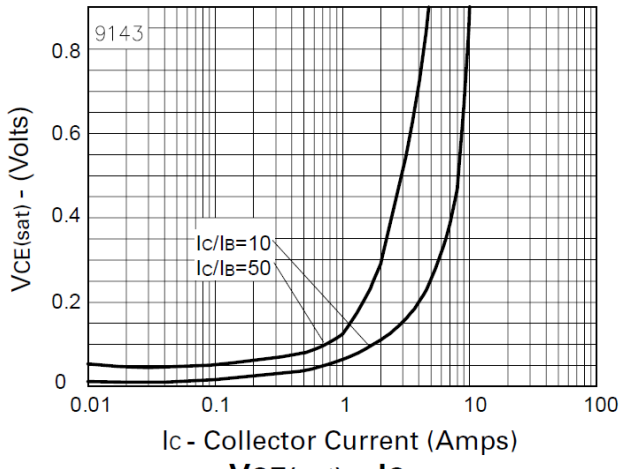
Pulse Power Dissipation

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

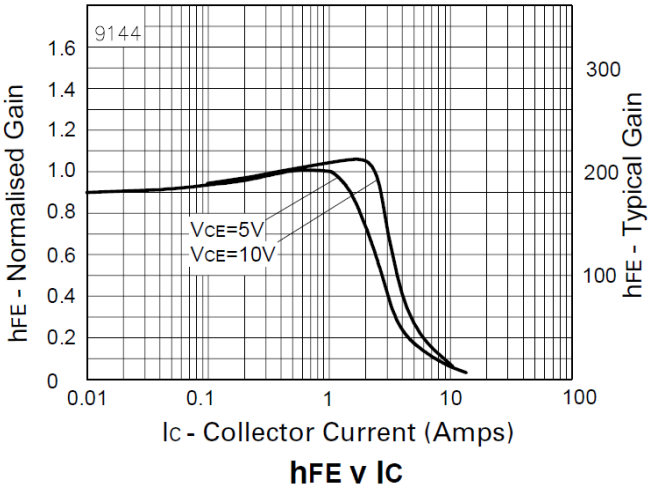
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	250	375	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage	BV_{CER}	250	375	—	V	I_C = 1µA, R_B ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	150	180	—	V	I_C = 1mA
Emitter-Base Breakdown Voltage	BV_{EBO}	7	8	—	V	I_E = 100µA
Collector Cut-Off Current	I_{CBO}	—	—	50 1	nA µA	V_{CB} = 200V V_{CB} = 200V, @T_A = +100°C
Collector Cut-Off Current	I_{CER}	—	—	50 1	nA µA	V_{CE} = 200V, R ≤ 1kΩ V_{CE} = 200V, @T_A = +100°C
Emitter Cut-Off Current	I_{EBO}	—	—	10	nA	V_{EB} = 6V
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(sat)}$	—	20 35 60 260	40 65 110 355	mV	I_C = 100mA, I_B = 5mA I_C =500mA, I_B = 50mA I_C =1A, I_B = 100mA I_C =5A, I_B = 500mA
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	—	—	1,250	mV	I_C =5A, I_B = 500mA
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(on)}$	—	—	1,100	mV	I_C = 5A, V_{CE} = 5V
DC Current Gain (Note 9)	h_{FE}	100 100 15 —	200 200 30 10	— 300 — —		I_C = 10mA, V_{CE} = 5V I_C = 1A, V_{CE} = 5V I_C = 5A, V_{CE} = 5V I_C = 10A, V_{CE} = 5V
Current Gain-Bandwidth Product (Note 9)	f_T	—	90	—	MHz	V_{CE} = 10V, I_C = 100mA f = 50MHz
Output Capacitance	C_{obo}	—	22	—	pF	V_{CB} = 10V, f = 1MHz
Switching Times	t_{on} t_{off}	—	66 2,130	—	ns ns	I_C = 1A, V_{CC} = 50V I_{B1} = -I_{B2} = 100mA

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

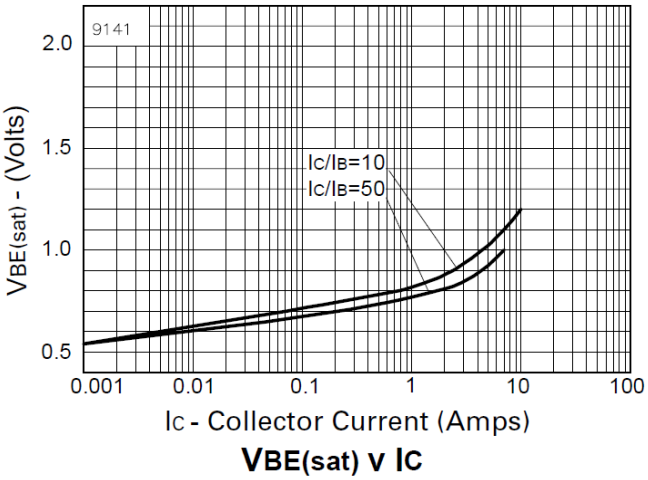
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)



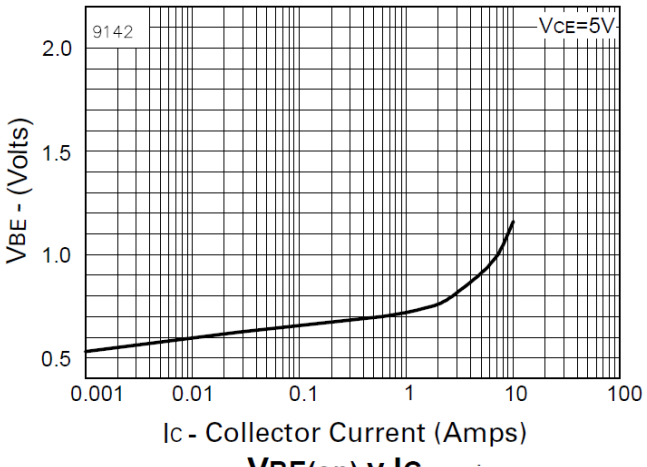
VCE(sat) v IC



hFE v IC



VBE(sat) v IC

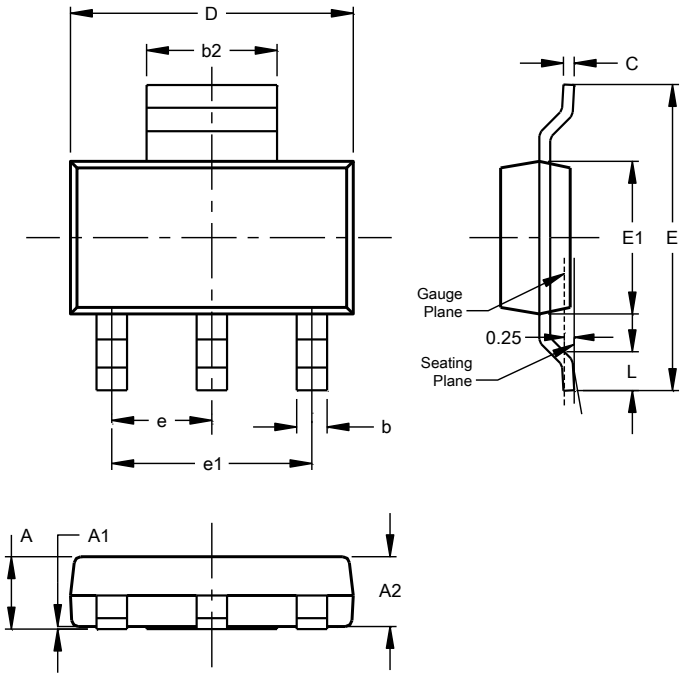


VBE(on) v IC

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

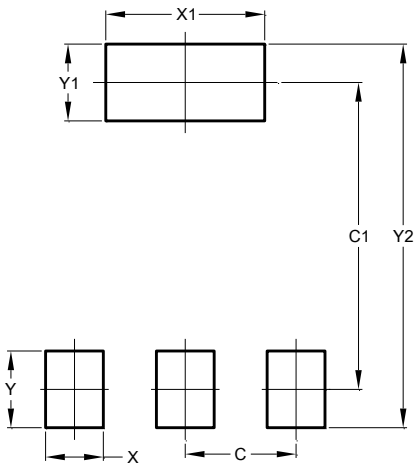


SOT223 (Type DN)			
Dim	**Min**	**Max**	**Typ**
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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